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### **KSD560**

### **Low Frequency Power Amplifier**

- Low Speed Switching Industrial Use
- Complement to KSB601



1.Base 2.Collector 3.Emitter

## **NPN Epitaxial Silicon Darlington Transistor**

### Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

| Symbol           | Parameter                                    | Value      | Units |
|------------------|--|------------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage                       | 150        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage                    | 100        | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage                         | 7          | V     |
| I <sub>C</sub>   | Collector Current (DC)                       | 5          | Α     |
| I <sub>CP</sub>  | *Collector Current (Pulse)                   | 8          | Α     |
| I <sub>B</sub>   | Base Current                                 | 0.5        | Α     |
| P <sub>C</sub>   | Collector Dissipation (T <sub>a</sub> =25°C) | 1.5        | W     |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> =25°C) | 30         | W     |
| T <sub>J</sub>   | Junction Temperature                         | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                          | - 55 ~ 150 | °C    |

<sup>\*</sup> PW≤10ms, Duty Cycle≤50%

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

| Symbol                | Parameter                             | Test Condition             | Min. | Тур. | Max. | Units |
|-----------------------|---------------------------------------|----------------------------|------|------|------|-------|
| I <sub>CBO</sub>      | Collector Cut-off Current             | $V_{CB} = 100V, I_{E} = 0$ |      |      | 1    | μΑ    |
| h <sub>FE1</sub>      | *DC Current Gain                      | $V_{CE} = 2V, I_{C} = 3A$  | 2K   | 6K   | 15K  |       |
| h <sub>FE2</sub>      |                                       | $V_{CE} = 2V, I_{C} = 5A$  | 500  |      |      |       |
| V <sub>CE</sub> (sat) | *Collector-Emitter Saturation Voltage | $I_C = 3A$ , $I_B = 3mA$   |      | 0.9  | 1.5  | V     |
| V <sub>BE</sub> (sat) | *Base-Emitter SaturationVoltage       | $I_C = 3A$ , $I_B = 3mA$   |      | 1.6  | 2    | V     |
| t <sub>ON</sub>       | Turn ON Time                          | $V_{CC} = 50V, I_{C} = 3A$ |      | 1    |      | μs    |
| t <sub>STG</sub>      | Storage Time                          | $I_{B1} = -I_{B2} = 3mA$   |      | 3.5  |      | μs    |
| $f_T$                 | Fall Time                             | $R_L = 16.7\Omega$         |      | 1.2  |      | μs    |

<sup>\*</sup> Pulse Test: PW≤350μs, Duty Cycle≤2% Pulsed

### $h_{\text{FE}}$ Classification

| Classification   | R           | 0           | Y            |
|------------------|-------------|-------------|--------------|
| h <sub>FE1</sub> | 2000 ~ 5000 | 3000 ~ 7000 | 5000 ~ 15000 |

# **Typical Characteristics**

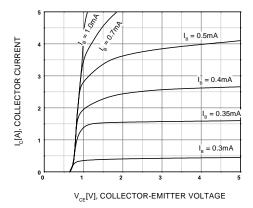


Figure 1. Static Characteristic

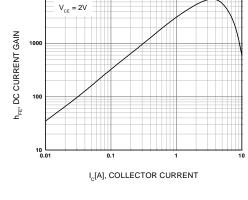


Figure 2. DC current Gain

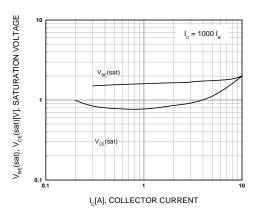


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

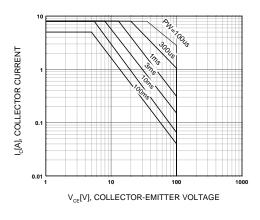


Figure 4. Safe Operating Area

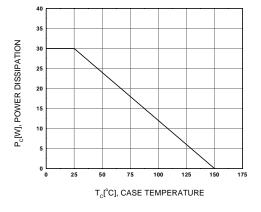
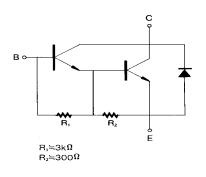


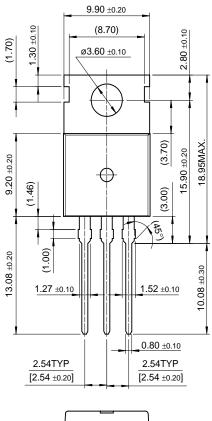
Figure 5. Power Derating

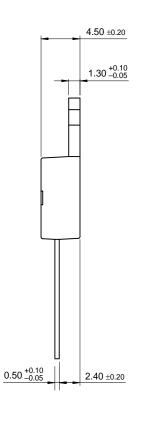


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# **Package Demensions**

# TO-220





10.00 ±0.20

Dimensions in Millimeters

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